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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SJ603

SWITCHING P-CHANNEL POWER MOS FET

DESCRIPTION

The 2SJ603 is P-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

FEATURES

• Super low on-state resistance:

 $R_{DS(on)1} = 48 \text{ m}\Omega \text{ MAX. (VGs} = -10 \text{ V, ID} = -13 \text{ A)}$

 $R_{DS(on)2}$ = 75 $m\Omega$ MAX. (Vgs = -4.0 V, Ip = -13 A)

• Low input capacitance:

 $C_{iss} = 1900 \text{ pF TYP.} (V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V})$

· Built-in gate protection diode

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SJ603	TO-220AB
2SJ603-S	TO-262
2SJ603-ZJ	TO-263
2SJ603-Z	TO-220SMD Note

Note TO-220SMD package is produced only in Japan.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	-60	V
Gate to Source Voltage (VDS = 0 V)	Vgss	∓20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	∓25	Α
Drain Current (pulse) Note1	ID(pulse)	∓70	Α
Total Power Dissipation (Tc = 25°C)	Рт	50	W
Total Power Dissipation (T _A = 25°C)	Рт	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	-25	Α
Single Avalanche Energy Note2	Eas	62.5	mJ

Notes 1. PW \leq 10 μ s, Duty cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = -30 V, R_G = 25 Ω , V_{GS} = -20 \rightarrow 0 V

(TO-220AB)



(TO-262)



(TO-263, TO-220SMD)



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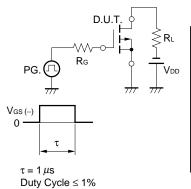
ELECTRICAL CHARACTERISTICS (TA = 25°C)

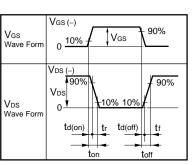
	•	•				
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Ipss	Vps = -60 V, Vgs = 0 V			-10	μΑ
Gate Leakage Current	lgss	$V_{GS} = \mp 20 \text{ V}, V_{DS} = 0 \text{ V}$			∓10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$	-1.5	-2.0	-2.5	٧
Forward Transfer Admittance	yfs	V _{DS} = -10 V, I _D = -13 A	10	21		S
Drain to Source On-state Resistance	RDS(on)1	V _G S = -10 V, I _D = -13 A		38	48	mΩ
	RDS(on)2	Vgs = -4.0 V, ID = -13 A		53	75	mΩ
Input Capacitance	Ciss	Vps = -10 V		1900		pF
Output Capacitance	Coss	V _G s = 0 V		350		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		140		pF
Turn-on Delay Time	td(on)	V _{DD} = -30 V, I _D = -13 A		10		ns
Rise Time	tr	V _G S = −10 V		11		ns
Turn-off Delay Time	td(off)	$R_G = 0 \Omega$		66		ns
Fall Time	tr			20		ns
Total Gate Charge	Q _G	V _{DD} = -48 V		38		nC
Gate to Source Charge	Qgs	V _{GS} = -10 V		7		nC
Gate to Drain Charge	Q _{GD}	I _D = -25 A		10		nC
Body Diode Forward Voltage	V _F (S-D)	IF = 25 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 25 A, VGS = 0 V		49		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ μs		100		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

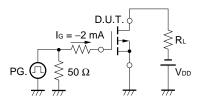
$PG \longrightarrow Starting T_{ch}$ $PG \longrightarrow Starting T_{ch}$ $PG \longrightarrow Starting T_{ch}$

TEST CIRCUIT 2 SWITCHING TIME



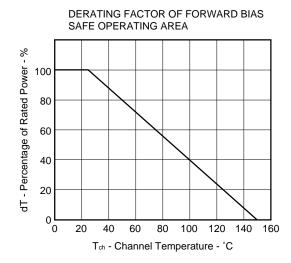


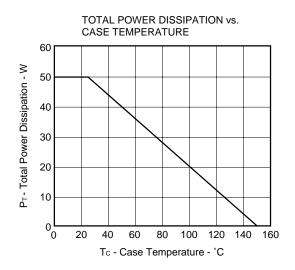
TEST CIRCUIT 3 GATE CHARGE



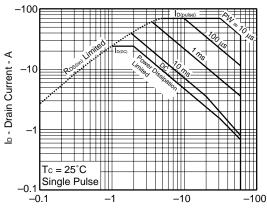


TYPICAL CHARACTERISTICS (TA = 25°C)



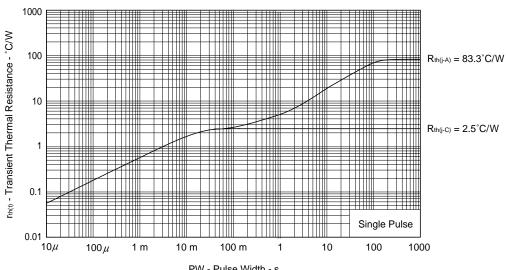


FORWARD BIAS SAFE OPERATING AREA



 $V_{\text{\scriptsize DS}}$ - Drain to Source Voltage - V

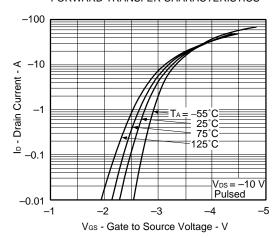
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



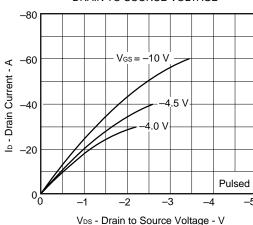
PW - Pulse Width - s

3

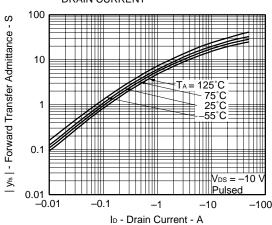
FORWARD TRANSFER CHARACTERISTICS



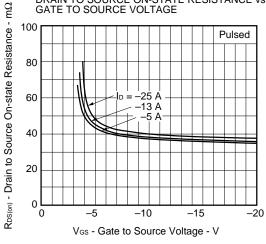
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



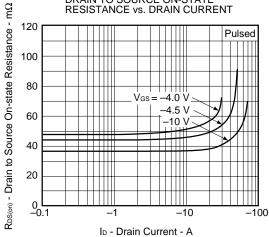
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



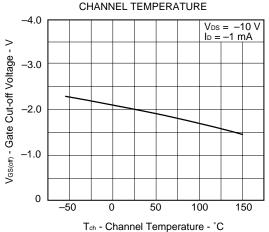
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



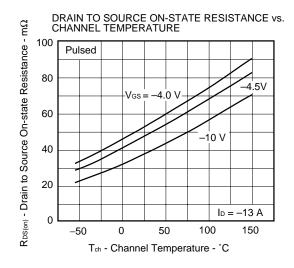
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

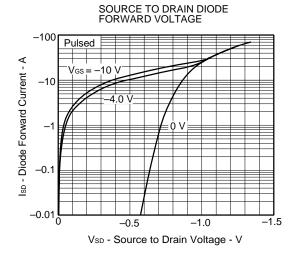


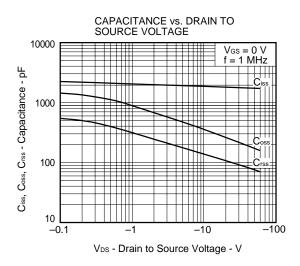
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

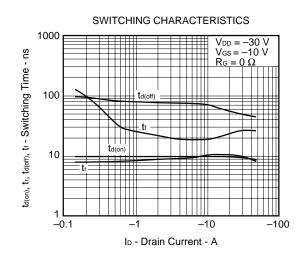


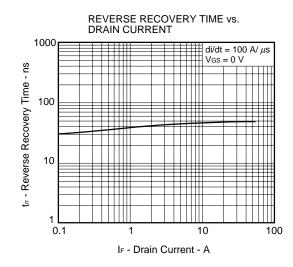


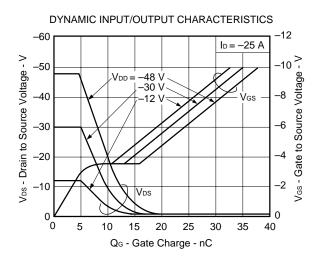




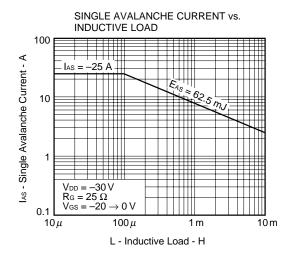


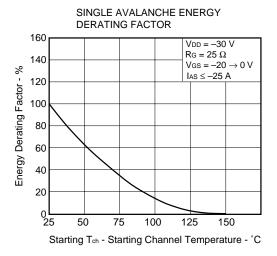






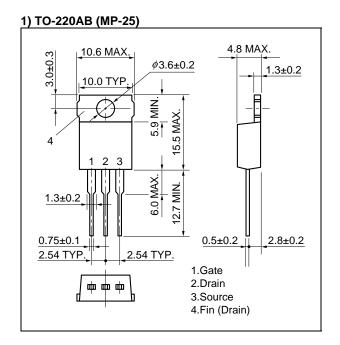
5

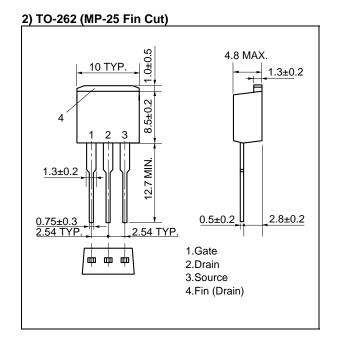


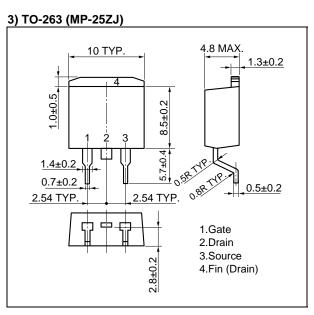


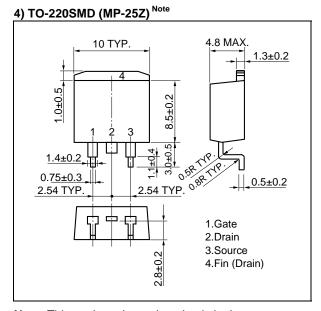


★ PACKAGE DRAWINGS (Unit: mm)



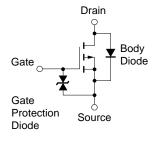






Note This package is produced only in Japan.

EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

Data Sheet D14648EJ3V0DS 7

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